

# MBR1630 - MBR1660

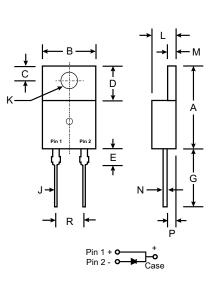
## **16A SCHOTTKY BARRIER RECTIFIER**

#### Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Plastic Material: UL Flammability Classification Rating 94V-0

#### **Mechanical Data**

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 2.24 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



TO-220AC						
Dim	Min	Max				
Α	14.22	15.88				
В	9.65	10.67				
С	2.54	3.43				
D	5.84	6.86				
E		6.35				
G	12.70	14.73				
J	0.51	1.14				
к	3.53Ø	4.09Ø				
L	3.56	4.83				
м	1.14	1.40				
N	0.30	0.64				
Р	2.03	2.92				
R	4.83	5.33				
All Dimensions in mm						

## Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	MBR 1630	MBR 1635	MBR 1640	MBR 1645	MBR 1650	MBR 1660	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	30	35	40	45	50	60	v
RMS Reverse Voltage	V <sub>R(RMS)</sub>	21	24.5	28	31.5	35	42	V
Average Rectified Output Current (Note 1) $@ T_C = 125^{\circ}C$	lo	16					A	
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	150					А	
Forward Voltage Drop @ $I_F = 16A$ , $T_C = 25^{\circ}C$ @ $I_F = 16A$ , $T_C = 125^{\circ}C$	V <sub>FM</sub>						75 65	V
Peak Reverse Current $@T_C = 25^{\circ}C$ at Rated DC Blocking Voltage $@T_C = 125^{\circ}C$	I <sub>RM</sub>	0.2 40		1.0 50		mA		
Typical Junction Capacitance (Note 2)	Cj	450					pF	
Typical Thermal Resistance Junction to Case (Note 1)		1.5			:	3		
Voltage Rate of Change (Rated V <sub>R</sub> )		1000 10,000					V/µs	
Operating and Storage Temperature Range		-65 to +150						°C

Notes: 1.Thermal resistance junction to case mounted on heatsink.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

